

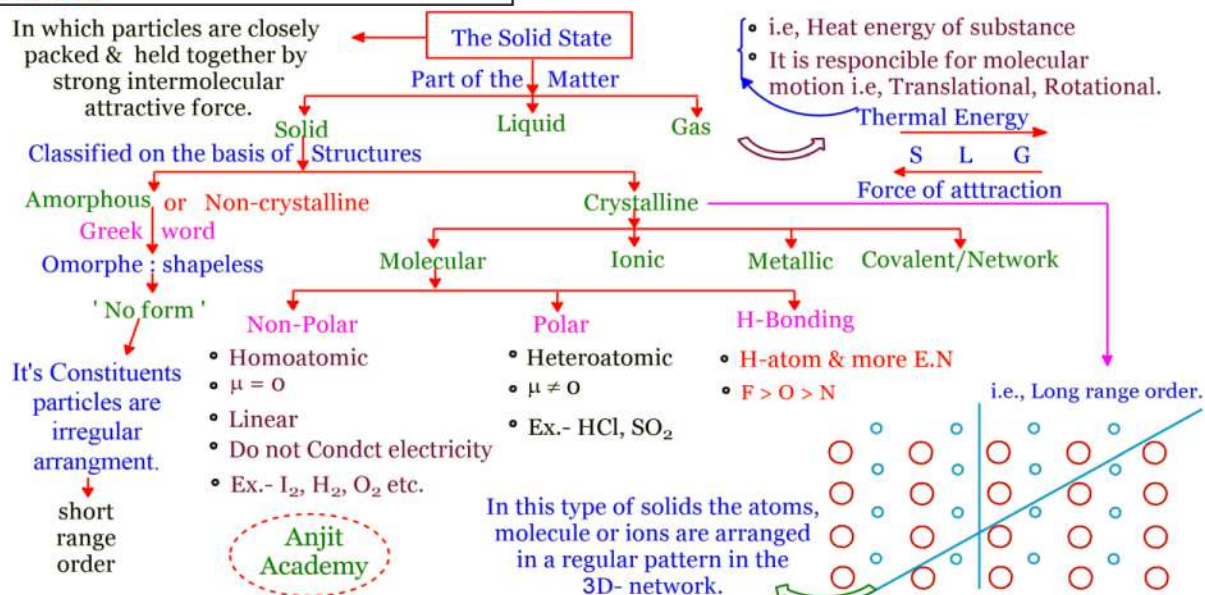
Super Short Tricky Chemistry By
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Conceptual Notes for NEET/JEE/Boards

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1. Introduction



1.1 Properties of solids:

- In solid state the particles are not able to move randomly.
- They have definite shape and volume.
- Solids have high density.
- Solids have high and sharp melting point which depends on the strength or value of binding energy.
- They are very low compressible.

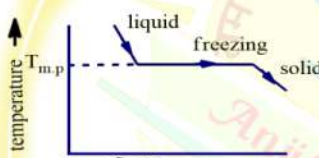
(f) They show very slow diffusion.

Note:

- Meting Point:** is the temp. at which solid melts at 1 atm. Pr. Is M.P of the solid.
- Molecular Motion:** Ocellate about the mean position (centre of mass)

1.2 Difference b/w Crystalline & Amorphous Solids :

Anisotropy: Crystalline solids are anisotropic in nature, that is, some of their physical properties like electrical resistance or refractive index show different values when measured along different directions in the same crystals. This arises from different arrangement of particles in different directions.

Property	Crystalline solids	Amorphous solids
Shape	Definite characteristic geometrical shape	Irregular shape
Melting point	Melt a sharp and characteristic temperature	Gradually soften over a range of temperature
Cleavage property	When cut with a sharp edged tool, they split into two pieces are plain and smooth	When cut with a sharp edged tool, they cut into two pieces with irregular surfaces
Heat of fusion	They have definite and characteristic value	They do not have definite value
Anisotropy	Anisotropic in nature except cubic crystals	Isotropic in nature
Nature	True solids	Pseudo solids or super cooled liquids
Order in arrangement of constituent particles	Long range order	Only short range order
Law of Crystallography	Follows	Does not follow
X-ray diffraction	Forms	Does not form
Cooling curve	Cooling curve is not smooth 	Cooling curve is smooth 
Examples	NaCl, Diamond, MgO, CaF ₂ , Quartz, Red P.	Glass, Rubber, Plastic, Quartz glass

Note :

- Glass are supercooled Liquid (due to viscosity)
- Ionic compound generally forms solid. (KCl)

3. NaCl (Rock Salt) do not conduct electricity, It conduct electricity only in molten or aqueous stage.

1.3 Classification of Crystalline Solids:

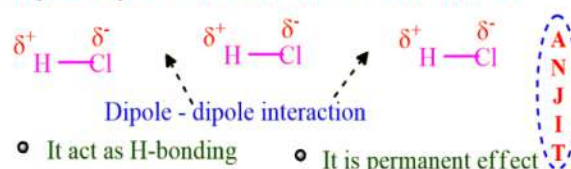
SN	Type of Crystal	Constituents Unit	Attractive Force	Example	M.P (K)	Physical Properties	Electrical Conductivity
1.	Molecular Solid ▪ Non-Polar ▪ Polar ▪ H-Bonding	Contains Molecules	London Force	H ₂	Low	soft	Bad conductor
			Dipole-Dipole Interaction	HCl	Low	soft	Insulator
			H-bonding	H ₂ O (ice)	Low	hard	Insulator
2.	Ionic Solid	Ions (+ve & -ve)	Electrostatic force of attraction 'or' Coulombic force	NaCl KCl	high	hard	NaCl (molten stage)
3.	Covalent 'or' Network solid	Atom	Covalent bonding	Diamond	4000 K	Hard	Insulator
				Graphite	soft	soft	Conductor
4.	Metallic Solid	Atom (kernel: +ve charge are held together by free e- charge)	Metallic force	Cu Fe Ag	Fairly high 4800K	soft	Conduction

Note : 01. London Force/ Dispersion Force :

- Frizz London in 1930, developed a force b/w two Non-polar molecules like- N₂, O₂, H₂ or monoatomic gases like- He, Ne, Ar etc. Due to momentary dipole and Induced dipole.
- These force only suitable for short distance.
- Their energies are in range 1-10 kJ/mol

Example : Dispersion force Order : C₄H₁₀ > C₃H₈ > C₂H₆ > CH₄
b/coz bigger molecules easily polarised.

02. Dipole-Dipole Interaction or Keesom Forces :

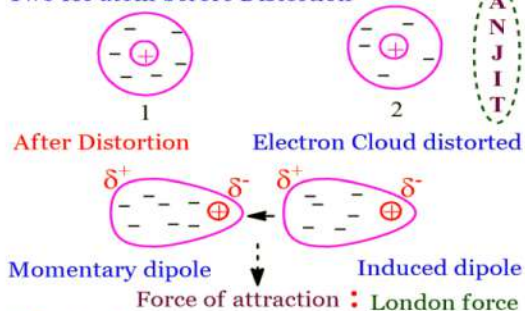


⇒ Relative strength of four intermolecular forces is:

Ionic > H-Bond > Dipole-dipole > Vander waaals forces

- The forces develop b/w polar mol. like-HCl, NO₂, SO₂ etc
- Compound having difference E.N act as polar.

Two He atom before Distortion



⇒ It depends on Two factors :

1. Molecular Size :

Dispersion force $\propto$ Mol. mass $\propto$ B.P

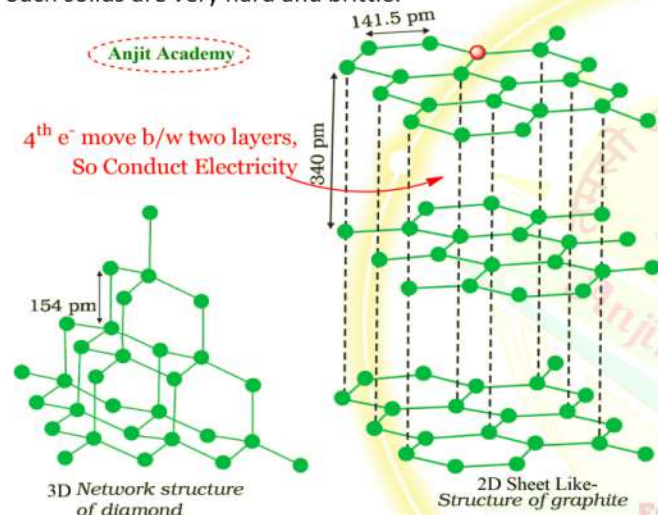
2. Molecular Geometry :

Dispersion force $\propto$ straight chain $\propto$ B.P

so, n- > iso- > neo-

1.4 Covalent or Network Solids:

Covalent bonds are strong and directional in nature; therefore, atoms are held very strongly at their positions. Such solids are very hard and brittle.



SN	Properties	Diamond	Graphite
1.	Force / Nature	Strong Covalent Bond (Hard). Mohs scale = 10 rating. (to check hardness of diamond)	Weak Vander Waal force of attraction (soft). Mohs scale = 1-2 rating.
2.	B.L	154 pm	141.5 pm

3.	Hybridisation	Sp ³	Sp ²
4.	Transparency	High refractive index (2.417). So, transparent.	It is black in colour & possesses metallic lustres
5.	Crystal System	Octahedral	Hexagonal
6.	Z (Effective Nuclear charge)	8 (4 = FCC + 4 = alternate Tetrahedron)	4
7.	Density	3.5 g/cm ³	2.3 g/cm ³
8.	r (refractive index)	2.414	-
9.	Lattice Structure	FCC	Hexagonal
10.	C.N	4	3
11.	Uses	Jewellery, Cutting	Pencil, Lubricant
			EMF of cell.

2 Crystal Lattice & Unit Cell

2.1 Crystal Lattice / Space lattice :

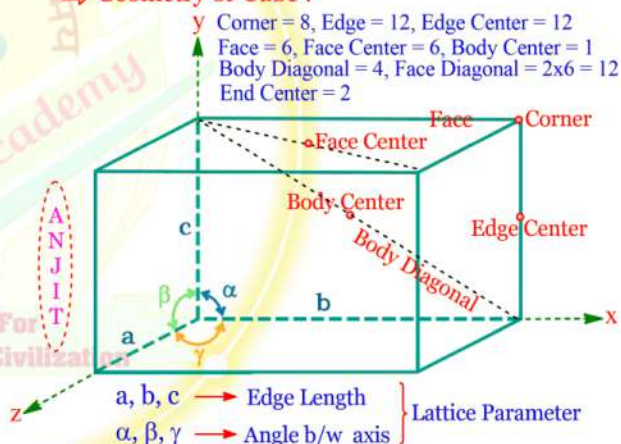
The arrangement of constituent atoms, ions and molecules in different sites in three dimensional space, with a long range order is called space lattice.

The following are characteristics of a crystal lattice:

- Each point in a lattice is called lattice point or lattice site
- Each point in a crystal lattice represents one constituent particle which may be an atom, a molecule or an ion.
- Lattice points are joined by straight lines to bring out the geometry of the lattice.

2.2 Geometry of Cube :

⇒ Geometry of Cube :



Note : Interfacial angles : Angle b/w the perpendiculars two intersecting faces called interfacial angles.

2.3 Type of Unit Cell :

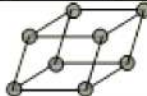
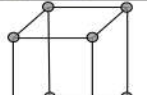
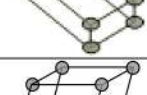
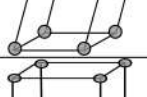
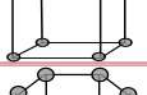
The smallest repeating unit in space lattice, which repeated again and again in different direction called unit cell.

Unit Cell		The smallest repeating unit in space lattice, which repeated again and again in different direction called unit cell.			
Primitive/Simple unit cells		Centred unit cells			
SC		Body-centred unit cells	Face-centred unit cells	End-centred unit cells	
		BCC	FCC	EC	
Constituent particles are present Only on the corner positions of a unit cell		Constituent particle (atom, molecule or ion) at its body-centre besides the ones that are at its corners.	Constituent particle present at the centre of each face, besides the ones that are at its corners.	at the centre of any two opposite faces besides the ones present at its corners.	
No. of Lattice : 8		8+1	8+6	8+2	
Contribution of atom : 1/8 = 25%		1 = 100%	1/2 = 50%	1/2 = 50%	
C.N (Coordination Number) : 6		8	12	4	
Z (Effective no. of Atoms) or : 1/8 x 8 = 1		1/8 x 8 + 1x1 = 2	1/8 x 8 + 6 x 1/2 = 4	1/8 x 8 + 2 x 1/2 = 2	
No. of atom per unit cell					

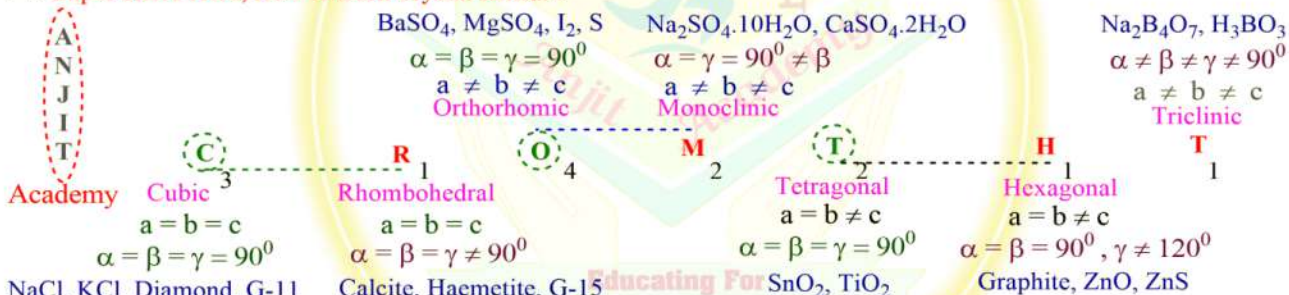
is the number of nearest atoms (or ions) surrounding an atom (or iron) in a crystal lattice.

3. Crystal System & Bravais Lattice System

These 14 Bravais lattices & 7 crystal system based on unit cell symmetry.

SN	Crystal systems	No. of B.L	Bravais lattices	Example	Unit cell parameters		Unit Cell
					Edge Length	Edge/Crystal angles	
1.	Cubic	3	SC, FCC, BCC	NaCl, KCl, Diamond, Cu, Ag, Au (G-11)	$a = b = c$	$\alpha = \beta = \gamma = 90^\circ$	
2.	Rhombohedral Or Trigonal	1	Primitive (SC)	Calcite, Haematite (Fe_2O_3), Quartz, As, Sb, Bi (G-15)	$a = b = c$	$\alpha = \beta = \gamma \neq 90^\circ$	
3.	Orthorhombic Or Rhombic	4	SC, FCC, BCC, End centre	BaSO_4 , MgSO_4 , I_2 , S.	$a \neq b \neq c$	$\alpha = \beta = \gamma = 90^\circ$	
4.	Triclinic	1	Primitive	H_3BO_3 , $\text{Na}_2\text{B}_4\text{O}_7$	$a \neq b \neq c$	$\alpha \neq \beta \neq \gamma \neq 90^\circ$	
5.	Monoclinic	2	Primitive, End centred	$\text{Na}_2\text{SO}_4 \cdot 10\text{H}_2\text{O}$, $\text{CaSO}_4 \cdot 2\text{H}_2\text{O}$	$a \neq b \neq c$	$\alpha = \beta = 90^\circ \neq \gamma$	
6.	Tetragonal	2	SC, BCC	SnO_2 , TiO_2	$a = b \neq c$	$\alpha = \beta = \gamma = 90^\circ$	
7.	Hexagonal	1	Primitive (SC)	Graphite, ZnO, ZnS	$a = b \neq c$	$\alpha = \beta = 90^\circ, \gamma = 120^\circ$	

⇒ Super Short Trick, How to learn Crystal Lattice :



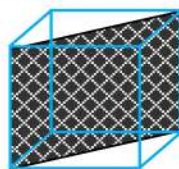
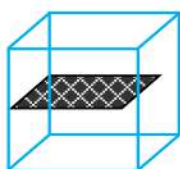
- NaCl, KCl, Diamond, G-11
- Match box has orthorhombic geometry
- Ice may give hexagonal or trigonal crystals
- Quartz may give hexagonal or trigonal crystals

4. Laws of Crystallography

4.1 Law of constancy of Symmetry :

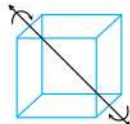
A crystal possess following three types of symmetry -

- Plane of symmetry :** It is an imaginary plane which passes through the centre of a crystal and can divide it into two equal portions which are exactly the mirror images to each other. So, Total = 3 + 6 = 9



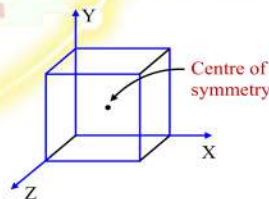
Face of cube / 2 = 3 Opposite edge / 2 = 6

2. Axis of symmetry :



∴ Faces/2 + Corners/2 + Edges /2 = 3 + 6 + 4 = 13

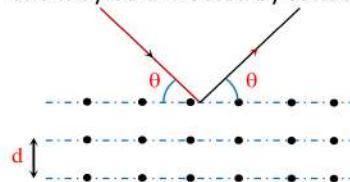
- Centre of symmetry :** It is a point in the crystal that any line drawn through it intersects the surface of the crystal at equal distance on either side. Hence, equal to = 1



A cubic crystal possesses total = 9 + 13 + 1 = 23 symmetry

4.2 X-ray study of the crystal : Bragg's Law :

X - rays are electromagnetic waves of short wavelength and may be diffracted by suitable diffracting centres.



$$2d \sin \theta = n\lambda$$

d → distance b/w two parallel (d_{hkl}) surface

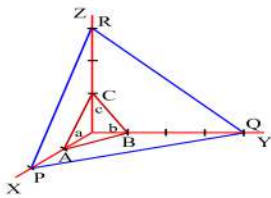
λ → wavelength, θ → Angle of deflection

n → no. of reflection 'or' order of reflection

4.3 Miller Indices (Plane & Direction) :

- It is used to calculate direction & plane of the crystal system by using h, k, l integer.

$$h = \frac{a}{\text{Intercept on the } x\text{-axis}}, k = \frac{b}{\text{Intercept on the } y\text{-axis}}, l = \frac{c}{\text{Intercept on the } z\text{-axis}}$$

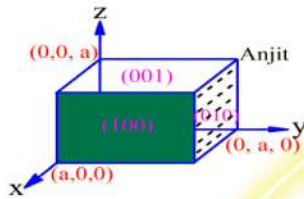


- The distance between the parallel planes in a crystal are designated as d_{hkl} for different cubic lattices these interplanar spacings are given by the following general formula as -

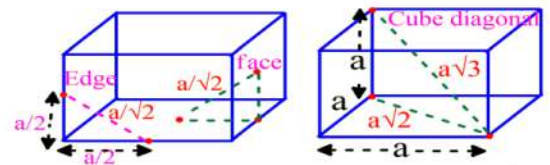
$$d_{hkl} = \frac{a}{\sqrt{h^2 + k^2 + l^2}}$$

where, a = length of the cube side & h, k, l = Miller indices of the plane

- Direction of miller indices $\rightarrow [hkl]$
Complete family $\rightarrow \langle hkl \rangle$ & Value $\rightarrow \{hkl\}$
- Procedure :
 - Intercept on the axis = x, y, z
 - Axis is parallel = ∞
 - take the reciprocal of fractional intercepts of its face on the various axes.



4.4 Length of Face diagonal & Cube diagonal :

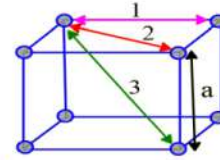


- Distance b/w two adjacent Face centre = $a/\sqrt{2}$
- Distance b/w two adjacent edge centre = $a/\sqrt{2}$
- Length of face diagonal = $a\sqrt{2}$
- Length of cube diagonal = $a\sqrt{3}$

4.5 First three nearest neighbour distance for primitive cubic unit cell will be :

Nearest distance $d = 2r$

1st nearest distance : SC (a), BCC ($\frac{a\sqrt{3}}{2}$), FCC ($\frac{a}{\sqrt{2}}$)



- 1st nearest neighbour distance = a
- 2nd nearest neighbour distance = $a\sqrt{2}$
- 3rd nearest neighbour distance = $a\sqrt{3}$

5. Cubic Closed Packing on Crystal

- In crystal, the constituents' particles (sphere) are arranged, In such a way that arrangement have minimum energy & max Stability.
- For max. stability the constituent particle are surrounded by max. no of neighbour particles.

Packing of Constituents in Crystals

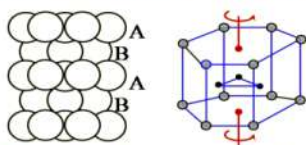
- 1 D - Close packing: are placed side by side in a row. Sphere are arranged in horizontal rows Only.
C.N = 2 In this arrangement, each spheres is in contact with two of its neighbours.

- 2 D - Close packing:
 - can be arranged in two different way to build crystal plane.
 - sphere are arranged Horizontal & Vertical alignment and so on.
 - In Hexagonal close packing arrangement is more dense (Stable) than square close packing (2D).

- 3 D - Close packing:

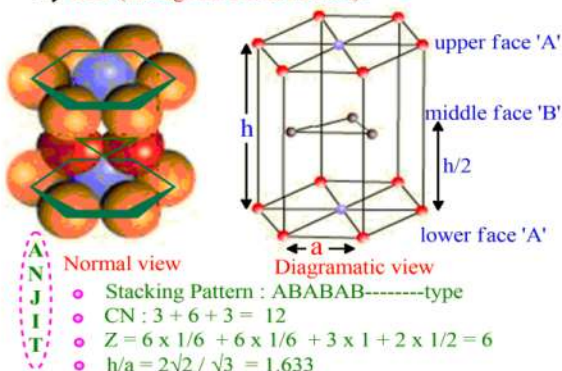
is obtained by stacking 2D layers one above the other.

Hexagonal close packing (hcp)

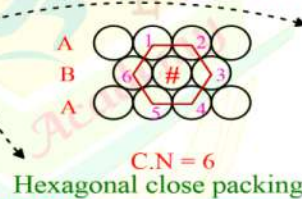


When the spheres in every layer is placed above only one type of voids (B or C) of previous layer, the spheres of every third layer lie strictly above the spheres of first layer. This arrangement if continued infinitely in the same sequence is represented as AB AB AB

⇒ HCP (Hexagonal Cubic Packed):



- Stacking Pattern : ABABAB.....type
- CN : $3 + 6 + 3 = 12$
- $Z = 6 \times \frac{1}{6} + 6 \times \frac{1}{6} + 3 \times 1 + 2 \times \frac{1}{2} = 6$
- $h/a = 2\sqrt{2} / \sqrt{3} = 1.633$

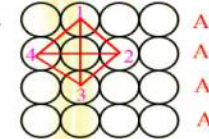


Hexagonal close packing

Stacking Pattern : ABABAB.....type arrangement

- In which the spheres in every second row are seated in the depression between the spheres of first row.

- In hexagonal close packing about 60.4% of available space is occupied by spheres



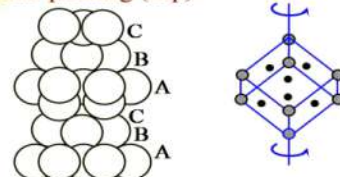
Square close packing

Stacking Pattern : AAA.....type

Each sphere in this arrangement is in contact with four other spheres.

Occupies only 52.4% of the space by spheres.

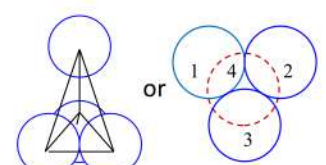
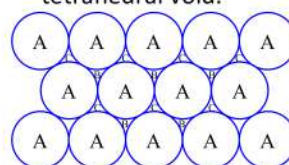
Cubic close packing (ccp)



When the spheres are placed alternatively above the voids B and C type, then the spheres of every fourth layer lie strictly above the spheres of first layer. This arrangement, If continued infinitely in the same sequence, is represented as ABC ABC ABC..... This arrangement is exactly same as fcc.

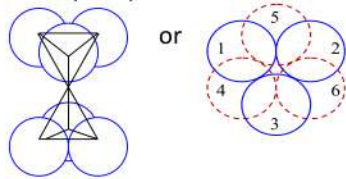
5.1 Tetrahedral void :

- This type of void is formed when a triangular void of a hexagonal closed plane is covered by an atom of another atomic layer.
- In any closed packed structure each atom has two tetrahedral void.



5.2 Octahedral void :

- The unoccupied space surrounded by six atoms or ions is called octahedral void.
- In any closed packed structure each atom has one octahedral void.
- This type of void is obtained when triangular void of another layer of HCP layer is placed over it.



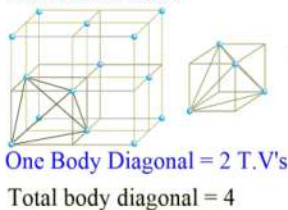
5.3 Location of void :

- If constituents Particles = N then, Octahedral Voids = N
And, No. of Tetrahedral Voids = 2N (Twice)

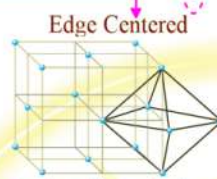
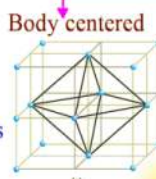
Locating Tetrahedral and Octahedral Voids

Let us take ccp / fcc ($z = 4$) structure and locate these voids in it.
 $z =$ Effective no. of atom 'or' No. of atom per unit cell

Tetrahedral Voids



Octahedral Voids



Total edge $\times$ contribution of atom = $12 \times 1/4 = 3$

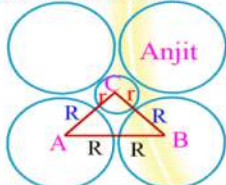
$$\therefore 3 + 1 = 4$$

5.4 Relation b/w Void radius & Sphere radius:

1. Octahedral Voids :

- Two equilateral triangle is formed b/w Six Sphere.
- $r/R = 0.414$

$\Rightarrow$ Octahedral Voids

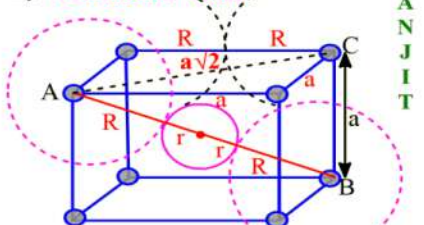


$$\begin{aligned} \Delta ABC, \therefore AB^2 &= AC^2 + BC^2 \\ \Rightarrow (2R)^2 &= (r + R)^2 + (r + R)^2 \\ \Rightarrow 2R &= 2\sqrt{(r + R)} \Rightarrow \sqrt{2} = r/R + 1 \\ \Rightarrow r/R &= 1 - 1.414 = 0.414 \end{aligned}$$

2. Tetrahedral Voids :

- One equilateral triangle is formed b/w four Sphere.
- $r/R = 0.225$

$\Rightarrow$ Tetrahedral Voids



$$\begin{aligned} 2R &= AC = a\sqrt{2} \Rightarrow R = a/\sqrt{2} \text{ -----(i)} \\ \Rightarrow AB^2 &= AC^2 + BC^2 \\ \Rightarrow (2r + 2R)^2 &= (a\sqrt{2})^2 + a^2 \\ \Rightarrow 2(r + R) &= \sqrt{3}a \text{ -----(ii)} \\ \text{from, eqn i \& ii, } r/R + 1 &= (\sqrt{3}) / (\sqrt{2}) \\ \Rightarrow r/R &= (\sqrt{3} - 1) / \sqrt{2} = 0.225 \end{aligned}$$

6. Mathematics Analysis of Cubic Crystal

6.1 Packing fraction (P.F.) & Packing Efficiency (P.E.):

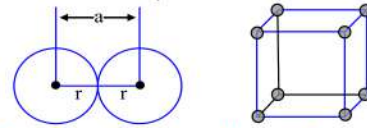
It is defined as ratio of the volume of the unit cell that is occupied by spheres of the unit cell to the total volume of the unit cell.

$$P.E. = \frac{\text{Volume occupied by total no. of sphere}}{\text{Vol. of Unit Cell}} \times 100$$

$$\Rightarrow P.E. = \frac{z \times \frac{4}{3}\pi r^3}{a^3} \times 100$$

(a) Simple cubic unit cell :

Number of atoms per unit cell $z = 8 \times 1/8 = 1$



And, "Atom touches along the axis." $r = a/2 \Rightarrow a = 2r$

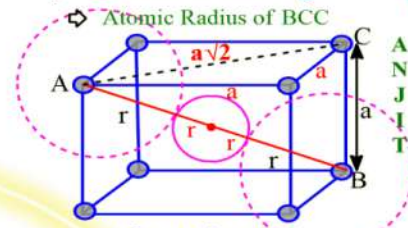
$$\therefore P.F. = \frac{1 \times \frac{4}{3}\pi r^3}{(2r)^3} = 0.52 = \frac{\pi}{6} \quad \text{So, \% P.F.} = 52.4 \%$$

% of void 'or' Empty space = $100 - 52 = 47.6 \%$

(b) Body centered cubic unit cell :

Number of atoms per unit cell $z = 8 \times 1/8 + 1 = 2$

And, "Atom touches along the body centre."



$$\begin{aligned} \Rightarrow AB^2 &= AC^2 + BC^2 \\ \Rightarrow (4r)^2 &= (a\sqrt{2})^2 + a^2 \\ \Rightarrow 4r &= \sqrt{3}a \Rightarrow r = \sqrt{3}a/4 \Rightarrow a = \frac{4r}{\sqrt{3}} \end{aligned}$$

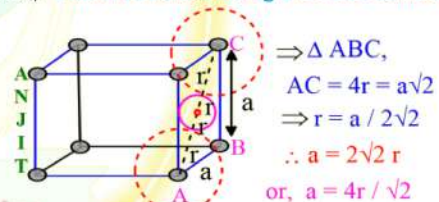
$$\therefore P.F. = \frac{2 \times \frac{4}{3}\pi r^3}{(4r/\sqrt{3})^3} = \frac{\pi\sqrt{3}}{6} = 0.68 \quad \text{so, } P.E. = 68 \%$$

% of void 'or' Empty space = $100 - 68 = 32 \%$

(c) Face centered cubic unit cell :

Number of atoms per unit cell $z = 4$

And, "Atom touches along the face centre."



$$\therefore P.F. = \frac{4 \times \frac{4}{3}\pi r^3}{(\frac{4r}{\sqrt{2}})^3} = \frac{\pi\sqrt{2}}{6} = 0.74 \quad \text{'or' \% P.F.} = 74 \%$$

% of void 'or' empty space = $100 - 74 = 26 \%$

Note: Any Metal crystal in FCC/BCC/Sc arrange & surface adjacent atom along the edge of unit cell 'or' Interfacial separation (distance) b/w the atoms at the edge = $a - 2r$

6.2 Density of Cubic Crystal :

It is defined as the ratio of mass of unit cell to the total volume of unit cell.

$$d = \frac{m}{v} = \frac{\text{mass per unit cell}}{\text{Volume of unit cell}} = \frac{Z \times \text{Mol. mass}}{N_A \times \text{volume of unit cell}}$$

$$\therefore d = \frac{Z \times M}{a^3 \times N_A} \quad \text{g/cm}^3 \quad \text{or} \quad \text{Kg/m}^3$$

Where, $Z \rightarrow$ is the number of atoms per unit cell

$N_A \rightarrow$ is the Avogadro number.

$a \rightarrow$ edge length / distance / unit cell length

6.3 Calculation of Ionic Radii or relation b/w r & a :

(a) NaCl Crystal = FCC Lattice :

$$a = 2(r_{Na^+} + r_{Cl^-}) \quad \text{or} \quad r_c + r_a = \frac{a}{2} \quad (\text{no. of nearest distance})$$

(b) CsCl Crystal = BCC Lattice :

$$a\sqrt{3} = 2(r_{Cs^+} + r_{Cl^-}) \quad \text{or} \quad r_c + r_a = \frac{a\sqrt{3}}{2}$$

6.4 Limiting Radius Ratios (R.R) & Structure :

R.R = (r^+) / (r^-)	C.N	Shape	Crystal	Ex.
< 0.155	2	Linear	-	-
0.155 – 0.225	3	Trigonal	-	B ₂ O ₃
0.225 – 0.414	4	Tetrahedral	FCC/CCP	ZnS

0.414 – 0.732	6	Octahedral	FCC	NaCl
0.732 – 1	8	Cubic	BCC	CsCl

7. Imperfection/Defects in Solid

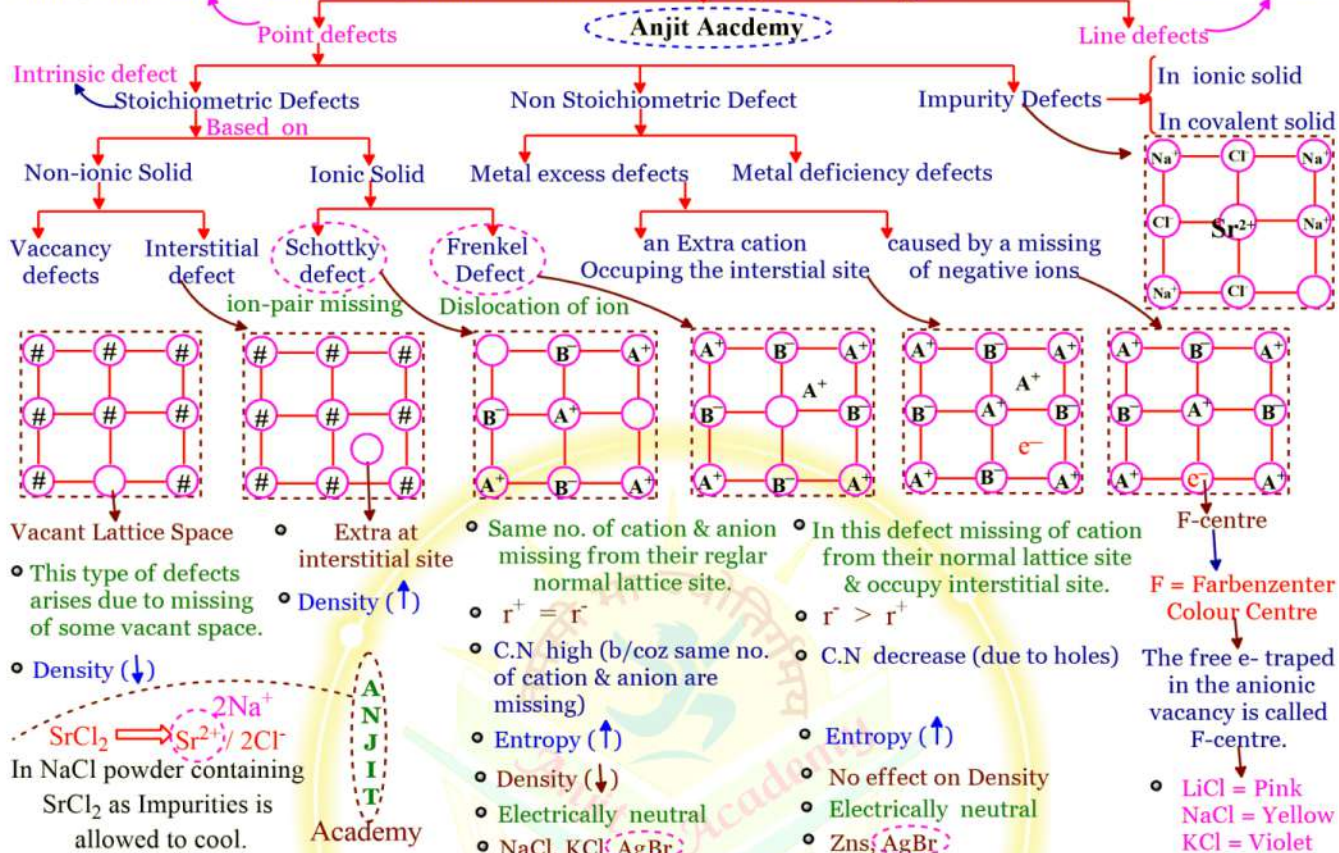
Imperfection in a crystal is the departure of constituent particles of the system from its regular position in the lattice.

Point defect arises due to irregularities from ideal arrangement around a point in a crystalline substance.

Imperfection / Defects

Line defects are the deviations in entire rows of lattice points.

i.e. irregularities in crystal

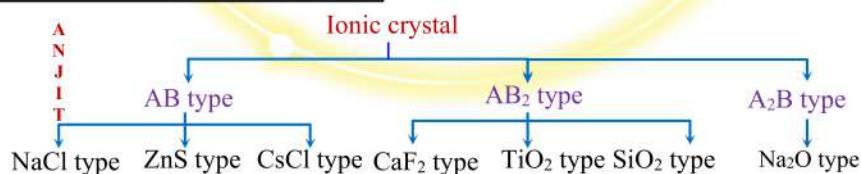


Note : AgBr Show Schottky & Frankel defects both, Why ?

- Schottky defect is observed in crystal High C.N and cation & anion have similar size.
- Frenkel defect is observed in those crystal whose there is large difference in size of cation & anion.

As, Ag⁺ is small in size & Cl⁻ is large in size which result in large difference in size of ions & also highly ionic.

7. Packing in ionic solids



Crystal Structure	Description 'or' Arrangement of ions	C.N	Z	
1. Rock Salt (NaCl - type)	CCP : Cl ⁻ ions in C.C.P, Na ⁺ ions occupy edge centre + body centre (all the octahedral voids.)	Na ⁺ – 6 Cl ⁻ – 6 ∴ C.N Ratio 6 : 6	4	Sodium chloride (NaCl)
2. Cesium Chloride (CsCl - type)	BCC : Cl ⁻ ions bcc arrangement the corner of a cube and Cs ⁺ ions in the body centre 'or' Vice versa.	Cs ⁺ – 8 Cl ⁻ – 8 ∴ C.N Ratio 8 : 8	1	CsCl

3. Zinc. Blende (ZnS)	CCP : S^{2-} ccp arrangement & Zn^{+2} ions occupy <i>alternate tetrahedral voids</i> i.e. only half of the total number of tetrahedral voids are occupied	$Zn^{+2} - 4$ $S^{2-} - 4$ $\therefore$ C. N Ratio 4 : 4	4	
4. Fluorite Struct. (CaF ₂ – type)	CCP : Ca^{+2} ions (+ve ions) in C.C.P. & F^- ions (-ve ions) in <i>all the tetrahedral voids</i> .	$Ca^{+2} - 8$ $F^- - 4$ $\therefore$ C. N Ratio 8 : 4	4	
5. Anti-fluorite Structure	CCP : B^{2-} Negative ions in CCP & Positive ions A^+ in <i>half tetrahedral voids</i> .	$Na^+ - 4$ $O^{2-} - 8$ $\therefore$ C. N Ratio 4 : 8	4	

Note : Rutile Structure (TiO₂) :
 O^{2-} : Forming HCP
 Ti^{4+} : $\frac{1}{2}$ of Octahedral voids

Compound Prop.	HCP	CCP/FCC	BCC
Arrangement of packing	Close packed	Close	Not close packed
Type of packing	ABAB.....	ABCABC.....	ABAB.....
Space occupied	74%	74%	68%
C.N	12	12	8
Effective no. of atoms (z)	6	4	2
Example	G-3, 4, 12 & Be, Mg	G-9,10,11 & Inert gas (Except He, Al)	G-1, 5, 6 & Ba, Fe

Effect of Temperature & Pressure on C.N. :
 Pressure ($\uparrow$) $\rightarrow$ C.N ($\uparrow$) & Temperature ($\uparrow$) $\rightarrow$ C.N ($\downarrow$)
 $NaCl$ $\xrightleftharpoons[Pr.(\uparrow), T(\uparrow)]{C.N = 6 : 6}$ $CsCl$ $\xrightleftharpoons[Pr.(\uparrow), T(\uparrow)]{C.N = 8 : 8}$

8. Properties of solids

8.1 Magnetic properties:

(a) Diamagnetic Material :

- Materials which are *weakly* repelled by magnetic fields.
- They contain paired electrons.
- Even no. of e- Except : 10 & 16e-.
- Examples of D.M are - C₆H₆, NaCl, S, ZnO, V₂O₅, TiO₂ etc.

(b) Paramagnetic material :

- Materials which are attracted by the magnetic field.
- They always contain unpaired electrons.
- In this material magnetic dipole tend to orient themselves parallel to the direction of the field and thus produce magnetization in the substance.
- Odd no. of e- with 10 & 16 e-.
- Examples : O₂, Cu⁺⁺, Fe⁺², Fe⁺³, Cr⁺³, CuO, NiO, Ti₂O₃ etc

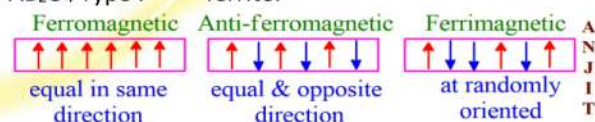
(c) Ferromagnetic material :

- Which are *strongly* attracted by magnetic lines of forces so, net magnetic moment *not equal to zero*.
- Ferromagnetism is due to *spontaneous* alignment of the magnetic dipole in the *same direction*.
- Each ferromagnetic material loses its magnetic character above a critical temp. This temp is called the **Curie temperature**.
- They contain a *number* of unpaired electrons
- Examples of these materials are Fe, Co, Ni etc.

(d) Anti-ferromagnetic materials :

- These are the materials, in which alignment of the dipole equal & opposite direction so as to give *zero net dipole* moment.
- MnO, FeO is the example of antiferromagnetic material.
- Ferrimagnetic materials** : These are the material in which dipoles are oriented in parallel and antiparallel direction in unequal numbers, so that there is a net magnetic moment. **Ex.-** Fe₃O₄, MgFe₂O₄, NiFe₂O₄ etc.

AB₂O₄ Type : ----- ferrite.



8.2 Dielectric Properties :

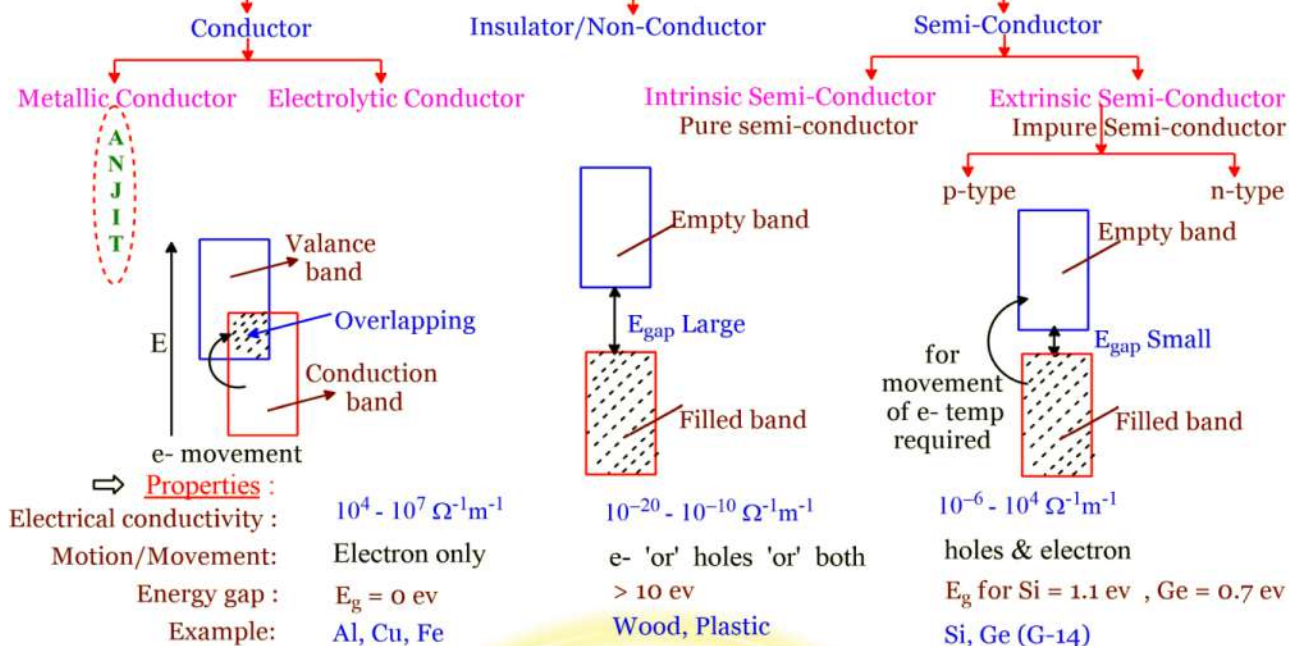
(1) Piezo electricity :

- When a polar crystal is subjected to a mechanical stress, electricity is produced. The electricity so produced is called piezo electricity.
- If an electric field is applied to a crystal, a mechanical stress is developed in the crystal. Thus, a piezo electric crystal acts as a mechanical-electrical transducer.

Example: Lead Zirconate (PbZrO₃)

- Pyro electricity** : Those materials which can produce small electric current. This phenomenon is termed as pyro electric effect. The electricity so produced is termed a pyro electricity.

8.3 Electrical Properties :

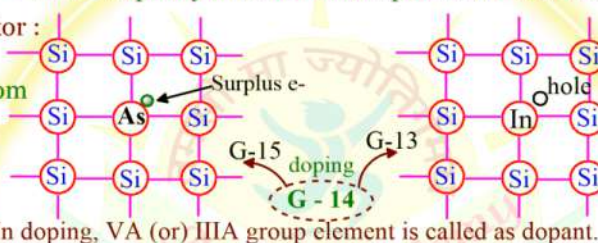


Extrinsic Semi-Conductor:

- Their conductivity is due to presence of impurity.
- Some impurity introduced in a pure semi-conductor (G-14) is called **Doping**.

n-Type Semi-conductor:

- n-stands for negative.
- penta-valent impurity atom
- e- rich impurities
- e- donor
- Lewis base



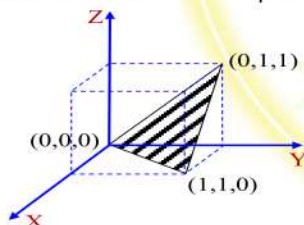
p-Type Semi-conductor:

- p- stands for positive.
- Tri-valent impurity atom
- e- deficient impurities
- e- acceptor
- Lewis acid
- One more e- is required, it is left as a vacant place on the atom.

Applications: n - type & p - type semi conductors both are used as- Diode, pnp or npn transistors.

Solved Important Questions

Ex.1 Determine the Miller indices of the shaded plane. Coordinate of the corners of the plane are shown -



Sol. A plane parallel to the plane between (0,0,0), (1,1,0) & (0, 1, 1) will intersect the axes at, $x = a$, $y = -b$ & $z = c$

a	b	c	
1	-1	1	intercepts
1	-1	1	reciprocals

Thus, the Miller indices are $(1, \bar{1}, 1)$ or $(\bar{1}, 1, \bar{1})$.

Ex.2 What is the simplest formula of a solid whose cubic unit cell has the atom A at each corner, the atom B at each face centre and a C atom at the body centre -
(A) AB_2C (B) A_2BC (C) AB_3C (D) ABC_3

Sol. number of corner atom (A) per unit cell = $8 \times 1/8 = 1$.
number of face-centered atoms (B) per unit cell = $6 \times 1/2 = 3$
 $\therefore$ no. of atoms (C) at the body centre per unit cell = 1.
Hence, the formula of the solid is AB_3C .

Ex.3 Select the correct statement (s) -

- (a) The C.N. of cation occupying a tetrahedral hole is 4
- (b) The C.N. of cation occupying an octahedral hole is 6
- (c) In Schottky defects, density of the lattice decreases
- (A) a, b (B) b, c (C) a, b, c (D) a, c

Sol. [C]

Ex.4 The unit cell of a metallic element of atomic mass 10^8 and density 10.5 g/cm^3 is a cube with edge length of 409 PM. The structure of the crystal lattice is -
(A) 0.128 (B) 1.42 (C) 3.22 (D) 4.22

Sol. For a face-centred cube, we have,
radius = $\frac{\sqrt{2}a}{4} = \frac{\sqrt{2} \times 0.361}{4} \text{ nm} = 0.128$.

Ex.5 Copper metal has a face-centred cubic structure with the unit cell length equal to 0.361 nm. Picturing copper ions in contact along the face diagonal, The apparent radius of a copper ion is -
(A) fcc (B) bcc (C) hcp (D) None

Sol. $\rho = \frac{Z \times M}{N \times a^3}$ Here, $M = 108$ $N_A = 6.023 \times 10^{23}$

Put on these values and solving we get -

$$a = 409 \text{ PM} = 4.09 \times 10^{-8} \text{ cm}$$

$$\therefore Z = 4 = \text{number of atoms per unit cell}$$

So, The structure of the crystal lattice is fcc.

Ex.6 A solid contains A^+ and B^- ions. The structure of solid is fcc for B^- ions and A^+ ions are present in one fourth of tetrahedral voids as well as in one fourth of octahedral voids. What is the simplest formula of solid?

Sol. The structure is fcc for B^- and hence

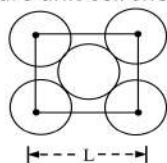
$$Z_B = 8 \times 1/8 + 6 \times 1/2 = 4$$

fcc contains 8 tetrahedral voids and four octahedral voids per unit cell and hence,
 $Z_A = 8 \times 1/4 + 4 \times 1/4 = 3$

$$\therefore \text{formula of solid} = \text{A}_3\text{B}_4$$

Multiple Choice Questions

- Q.7** In a solid AB having the NaCl structure, A atoms occupy the corners of the cubic unit cell. If all the face centered atoms along one of the axes are removed, then the resultant stoichiometry of the solid is –
 (A) AB_2 (B) A_2B (C) A_4B_3 (D) A_3B_4
- Q.8** A substance A_xB_y crystallizes in a face centered cubic (FCC) lattice in which atoms 'A' occupy each corner of the cube and atoms 'B' occupy the centres of each face of the cube. Identify the correct composition of the substance A_xB_y
 (A) AB_3 (B) A_4B_3 (C) A_3B
 (D) Composition can't be specified
- Q.9** Alternate tetrahedral void in FCC are occupied in
 (A) NaCl (B) ZnS (C) CaF_2 (D) Na_2O
- Q.10** The correct statement(s) regarding defects in solids is(are) –
 (A) Frenkel defect is usually favoured by a very small difference in the size of cation and anion
 (B) Frenkel defect is a dislocation defect
 (C) Trapping of an electron in the lattice leads to the formation of F-center
 (D) Schottky defects have no effect on the physical properties of solids
- Q.11** The packing efficiency of the two-dimensional square unit cell shown below is –



- (A) 39.27 % (B) 68.02 % (C) 74.05 % (D) 78.54 %

- Q.12** For an element of FCC crystal lattice having edge length 400 pm, calculate the maximum diameter of an atom which can be placed in interstitial site so that the structure remain same.
- Q.13** For a cubical system the following information are available. Edge length = $5\text{\AA}$; density = 2 gm/cm^3 , Atomic wt. = 75
 Determine the radius of the atom in pm ?
- Q.14** Match the crystal system/unit cells mentioned in Column-I with their characteristic feature mentioned in Column-II.

Column-I	Column-II
(A) simple cubic and face centred cubic	(P) have these cell parameters $a = b = c$ & $\alpha = \beta = \gamma$
(B) cubic and rhombohedral	(Q) are two crystal systems
(C) cubic and tetragonal	(R) have only two crystallographic angles of 90°
(D) hexagonal and monoclinic	(S) belong to same crystal system

- Q.15** CsBr has cubic structure with edge length 4.3. The shortest inter ionic distance in between Cs^+ & Br^- is
 (A) 3.72 (B) 1.86 (C) 7.44 (D) 4.3
- Q.16** In the sodium chloride structure, each Na^+ ion is surrounded by six Cl^- ions nearest neighbours and Na^+ ion next nearest neighbours –
 (A) 4 (B) 8 (C) 6 (D) 12
- Q.17** The coordination number of a metal crystallized in a hexagonal close packed structure is
 (A) 12 (B) 4 (C) 8 (D) 6
- Q.18** A metallic element crystallizes into a lattice containing sequence of layers of ABABAB..... This packing of sphere leaves out voids in the lattice. What percentage by volume of this space is empty space ?
- Q.19** Chromium metal crystallizes with a body centered cubic lattice. The length of the unit cell is found to be 287 pm. Calculate the atomic radius. What would be the density of chromium in g/cm^3 ?
- Q.20** A unit cell of sodium chloride has four formula units. The edge length of the unit cell is 0.564 nm. What is the density of sodium chloride?
- Q.21** A metal crystallizes into two cubic phases, face centered cubic (fcc) and body centered cubic (bcc), whose unit cell length are 3.5 and $3.0\text{\AA}$, respectively. Calculate the ratio of density of fcc and bcc.
- Q.22** If an element (at. wt. = 50) crystallizes in fcc lattice, with $a = 0.50\text{ nm}$. What is the density of unit cell if it contains 0.25% schottky defects (use $N_A = 6 \times 10^{23}$)
 (A) 2.0 g/cc (B) 2.66 g/cc
 (C) 3.06 g/cc (D) none of these
- Q.23**
- | Column-I | Column-II |
|-------------------------|---------------------------|
| (A) Spinel structure | (i) $ZnAl_2O_4$ |
| (B) Glass | (ii) Pseudo solid |
| (C) 6 : 6 Co-ordination | (iii) NaCl type structure |
| (D) Plastics | (iv) Super cooled liquid |
- Q.24** In fcc lattice, A, B, C, D atoms are arranged at corner, face centre, octahedral void and tetrahedral void respectively, then the body diagonal contains :
 (A) 2A, C, 2D (B) 2A, 2B, 2C
 (C) 2A, 2B, D (D) 2A, 2D
- Q.25** The radius of Ag^+ ion is 126 pm while that of I^- ion is 216 pm. The co-ordination number of Ag in AgI is –
 (A) 2 (B) 4 (C) 6 (D) 8



7. D	8. A	9. B	10. B, C	11. D	12. 117.1 Pm	13. 217 Pm
14.	A $\rightarrow$ (P, S), B $\rightarrow$ (P, Q), C $\rightarrow$ (Q), D $\rightarrow$ (Q, R)					15. A
16. D	17. A	18. 25.6%	19. 7.3 g/cm ³	20. 2.16 g/cm ³	21. 1.259	22. B
23.	A $\rightarrow$ (i); B $\rightarrow$ (ii), (iv); C $\rightarrow$ (iii); D $\rightarrow$ (ii), (iv)					24. A
						25. C